DG9431





Low-Voltage Single SPDT Analog Switch

DESCRIPTION

The DG9431 is a single-pole/double-throw monolithic CMOS analog device designed for high performance switching of analog signals. Combining low power, high speed (t_{ON} : 35 ns, t_{OFF} : 20 ns), low on-resistance ($r_{DS(on)}$: 20 Ω) and small physical size (TSOP-6), the DG9431 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG9431 is built on Vishay Siliconix's low voltage BCD-15 process. Minimum ESD protection, per Method 3015.7, is 2000 V. An epitaxial layer prevents latchup. Break-before -make is guaranteed for DG9431.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with 100 % matte tin device terminations, the lead (Pb)-free "-E3" suffix is being used as a designator.

FEATURES

- Low Voltage Operation (+ 2.7 to + 5 V)
- Low On-Resistance r_{DS(on)}: 20 Ω
- Fast Switching t_{ON}: 35 ns, t_{OFF}: 20 ns
- Low Leakage I_{COM(on)}: 200-pA max
- Low Charge Injection QINJ: 1 pC
- Low Power Consumption
- TTL/CMOS Compatible
- ESD Protection > 2000 V (Method 3015.7)
- Available in TSOP-6 and SOIC-8
- · Lead (Pb)-Free Version is RoHS Compliant

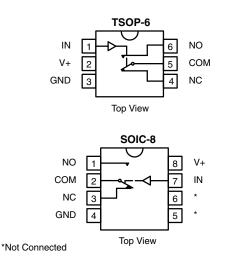
BENEFITS

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- Reduce Board Space (TSOP-6)

APPLICATIONS

- · Battery Operated Systems
- Portable Test Equipment
- Sample and Hold Circuits
- Cellular Phones
- Communication Systems
- Military Radio
- PBX, PABX Guidance and Control Systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE | | | | |
|-------------|-----|-----|--|--|
| Logic | NC | NO | | |
| 0 | ON | OFF | | |
| 1 | OFF | ON | | |

 $\begin{array}{l} \text{Logic "0"} \leq 0.8 \ \text{V} \\ \text{Logic "1"} \geq 2.4 \ \text{V} \end{array}$

| ORDERING INFORMATION | | | | |
|----------------------|---------|--|--|--|
| Temp Range | Package | Part Number | | |
| - 40 to 85 °C | TSOP-6 | DG9431DV-T1 DG9431DV-T1-E3 (Lead (Pb)-free) | | |
| | SOIC-8 | DG9431DY-T1 DG9431DY-T1-E3 (Lead (Pb)-free) | | |

* Pb containing terminations are not RoHS compliant, exemptions may apply

Document Number: 70831 S-71009–Rev. D, 14-May-07



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| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|-------------------------------------|---------------------|------|--|--|
| Parameter | | Limit | Unit | | |
| Reference V+ to GND | - 0.3 to + 13 | V | | | |
| IN, COM, NC, NO ^a | | - 0.3 to (V+ + 0.3) | 7 V | | |
| Continuous Current (Any Terminal) | | ± 20 | mA | | |
| Peak Current (Pulsed at 1 ms, 10 % duty cycle) | | ± 40 | IIIA | | |
| ESD (Method 3015.7) | | > 2000 | V | | |
| Storage Temperature (D Suffix) | | - 65 to 125 | °C | | |
| Power Dissipation (Packages) ^b | 8-Pin Narrow Body SOIC ^c | 400 | mW | | |

Notes:

a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC Board.
c. Derate 6.5 mW/°C above 75 °C.

| Parameter | | Test Conditions Unless Otherwise Specified $V+ = 3 V, \pm 10 \%, V_{IN} = 0.8 \text{ or } 2.4 V^{e}$ | | D Suffix - 40 to 85 °C | | | | |
|--|--------------------------------------|--|-------------------|----------------------------------|------------------|------------------|----------|--|
| | Symbol | | Temp ^a | Min ^c | Тур ^ь | Max ^c | Unit | |
| Analog Switch | | | | | | | <u> </u> | |
| Analog Signal Range ^d | V _{ANALOG} | | Full | 0 | | 3 | V | |
| Drain-Source On-Resistance | r _{DS(on)} | V_{NO} or V_{NC} = 1.5 V, V+ = 2.7 V I _{COM} = 5 mA | Room Full | | 30 | 50 80 | Ω | |
| r _{DS(on)} Match ^d | $\Delta r_{DS(on)}$ | $V_{NO} \text{ or } V_{NC} = 1.5 \text{ V}$ | Room | | 0.4 | 2 | | |
| r _{DS(on)} Flatness ^f | r _{DS(on)} Flatness | V_{NO} or V_{NC} = 1 and 2 V | Room | | 4 | 8 | | |
| NO or NC Off Leakage Current ^g | I _{NO/NC(off)} | $V_{\rm NO}~{\rm or}~V_{\rm NC}$ = 1 V/2 V, $V_{\rm COM}$ = 2 V/1 V | Room Full | - 100 - 5000 | 5 | 100 5000 | pА | |
| COM Off Leakage Current ^g | I _{COM(off)} | V_{COM} = 1 V/2 V, V_{NO} or V_{NC} = 2 V/1 V | Room Full | - 100 - 5000 | 5 | 100 5000 | | |
| Channel-On Leakage Current ^g | I _{COM(on)} | $V_{COM} = V_{NO} \text{ or } V_{NC} = 1 \text{ V/2 V}$ | Room Full | - 200 - 10000 | 10 | 200 10000 | | |
| Digital Control | <u>.</u> | | | | | | | |
| Input Current | I _{INL} or I _{INH} | | Full | | 1 | | μA | |
| Dynamic Characteristics | | | | | | - | - | |
| Turn-On Time | t _{ON} | | Room Full | | 50 | 120 200 | | |
| Turn-Off Time | t _{OFF} | V_{NO} or V_{NC} = 1.5 V | Room Full | | 20 | 50 120 | ns | |
| Break-Before-Make Time | t _d | | Room | 3 | 20 | | | |
| Charge Injection | Q _{INJ} | C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω | Room | | 1 | 5 | рС | |
| Off-Isolation | OIRR | R_L = 50 Ω, C_L = 5 pF, f = 1 MHz | Room | | - 74 | | dB | |
| Source Off Capacitance | C _{S(off)} | f = 1 MHz | Room | | 7 | | ~ - | |
| Channel-On Capacitance | C _{D(on)} | 1 = 1 MH2 | Room | | 32 | | pF | |
| Power Supply | | | | | | | | |
| Power Supply Range | V+ | | | 2.7 | | 12 | V | |
| Power Supply Current | l+ | V+ = 3.3 V, V _{IN} = 0 or 3.3 V | | | | 1 | μA | |



| Parameter | | Test Conditions Unless Otherwise Specified $V+ = 5 V, \pm 10 \%, V_{IN} = 0.8 \text{ or } 2.4 V^{e}$ | | D Suffix - 40 to 85 °C | | | | |
|---|--------------------------------------|--|-------------------|----------------------------------|------------------|------------------|------|--|
| | Symbol | | Temp ^a | Min ^c | Тур ^ь | Max ^c | Unit | |
| Analog Switch | • | | | • | | • | | |
| Analog Signal Range ^d | V _{ANALOG} | | Full | 0 | | 5 | V | |
| Drain-Source On-Resistance | r _{DS(on)} | V_{NO} or V_{NC} = 3.5 V, V+ = 4.5 V I _{COM} = 5 mA | Room Full | | 20 | 30 50 | | |
| r _{DS(on)} Match ^d | $\Delta r_{DS(on)}$ | $V_{NO} \text{ or } V_{NC} = 1.5 \text{ V}$ | Room | | 0.4 | 2 | Ω | |
| r _{DS(on)} Flatness ^f | r _{DS(on)} Flatness | V_{NO} or V_{NC} = 1, 2 and 3 V | Room | | 2 | 6 | | |
| NO or NC Off Leakage Current | I _{NO/NC(off)} | V_{NO} or V_{NC} = 1 V/4 V, V_{COM} = 4 V/1 V | Room Full | - 100 - 5000 | 10 | 100 5000 | pА | |
| COM Off Leakage Current | I _{COM(off)} | V_{COM} = 1 V/4 V, V_{NO} or V_{NC} = 4 V/1 V | Room Full | - 100 - 5000 | 10 | 100 5000 | | |
| Channel-On Leakage Current | I _{COM(on)} | Note that $V_{COM} = V_{NO} \text{ or } V_{NC} = 1 \text{ V/4 V}$ | | - 200 - 10000 | | 200 10000 | | |
| Digital Control | | | | | | | | |
| Input Current | I _{INL} or I _{INH} | | Full | | 1 | | μA | |
| Dynamic Characteristics | | | | | | | | |
| Turn-On Time | t _{ON} | V_{NO} or V_{NC} = 3.0 V | Room Full | | 35 | 75 150 | | |
| Turn-Off Time | t _{OFF} | | Room Full | | 20 | 50 100 | ns | |
| Break-Before-Make Time | t _d | | Room | 3 | 10 | | 1 | |
| Charge Injection | Q _{INJ} | C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω | Room | | 2 | 5 | pC | |
| Off-Isolation | OIRR | $R_L = 50 \ \Omega$, $C_L = 5 \ pF$, $f = 1 \ MHz$ | Room | | - 74 | | dB | |
| NC and NO Capacitance | C _(off) | 6 d MIL- | Room | | - 7 | | pF | |
| Channel-On Capacitance | C _{D(on)} | f = 1 MHz | Room | | 32 | | p | |
| Power Supply | | | | | | | | |
| Power Supply Range | V+ | | | 2.7 | | 12 | V | |
| Power Supply Current | l+ | V+ = 5.5 V, V _{IN} = 0 or 5.5 V | | | | 1 | μA | |

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

d. Guarantee by design, nor subjected to production test.

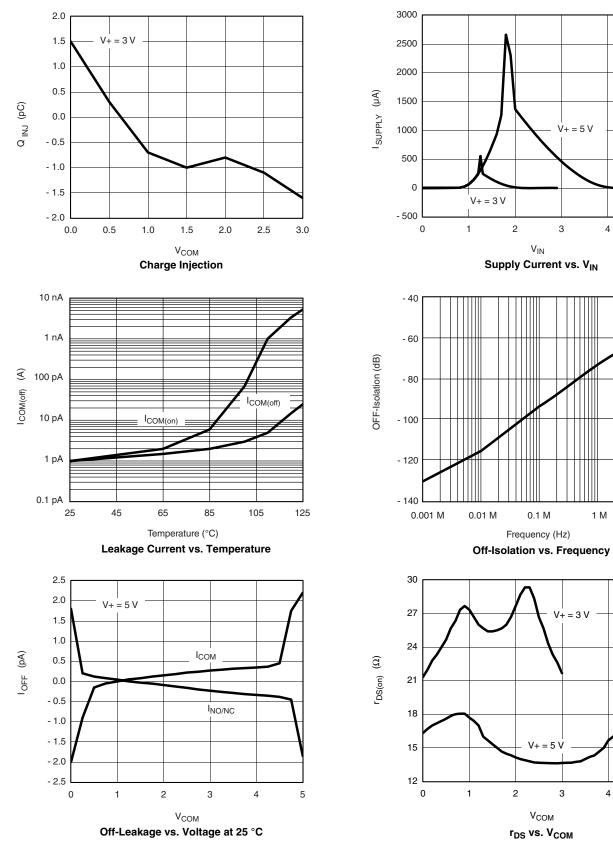
e. V_{IN} = input voltage to perform proper function.

f. Difference of min and max values.

g. Guraranteed by 5-V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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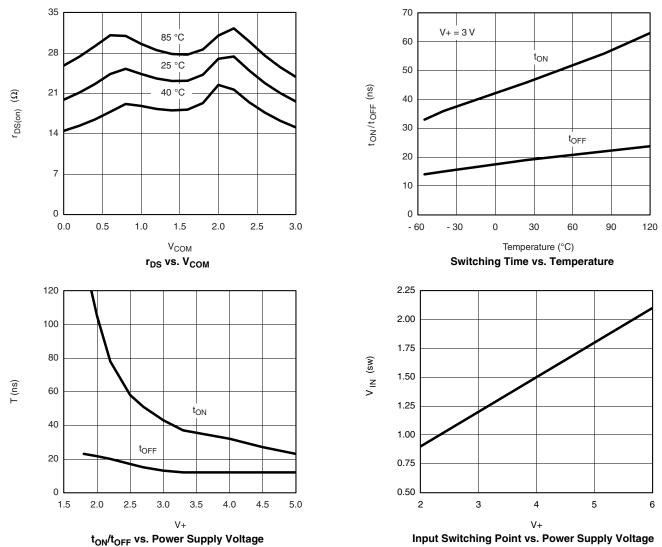
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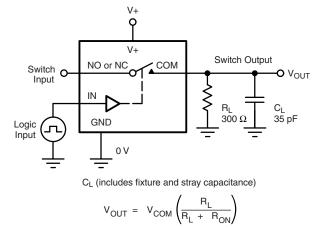
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

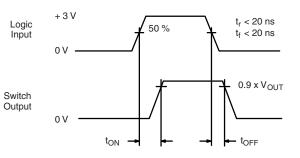


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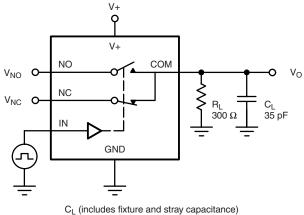






Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.





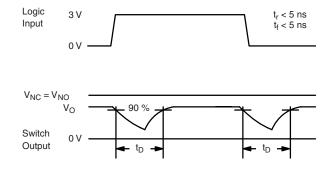


Figure 2. Break-Before-Make Interval

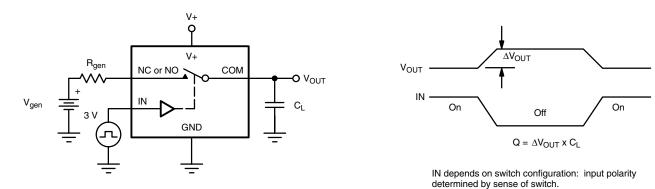


Figure 3. Charge Injection

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TEST CIRCUITS

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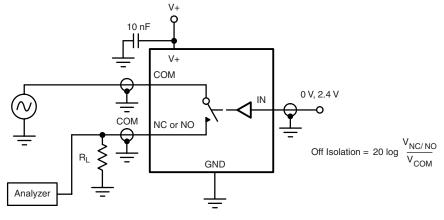


Figure 4. Off-Isolation

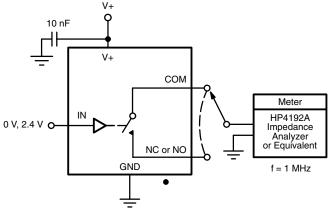


Figure 5. Channel Off/On Capacitance

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Document Number: 70831 S-71009–Rev. D, 14-May-07



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